

RESEARCH ARTICLE

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2023, 7, 2251A room-temperature moisture-stabilized
metal-free energetic ferroelectric material
for piezoelectric generation†Jun Wang, Xiao-Xian Chen, Le Ye, Ya-Ping Gong, Yu Shang and
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Metal-free molecule-based ferroelectrics that are degradable and exhibit tunable structures, low production costs, and “soft” textures have prospects for sensing and piezoelectric generation applications, but the instances integrating multiple functionalities are very rare. Herein, we proved that an energetic material based on ternary perchlorate salt, (1-methyl-1,4-diazabicyclo-[2.2.2]octane-1,4-diium)(NH₄)(ClO₄)₃ (DAP-M4), is simultaneously a rare room-temperature ferroelectric crystal with a low hygroscopicity (a weight increase of less than 0.02% under 100% relative humidity), an ultrawide band gap of 5.4 eV, “soft” mechanical properties (Young’s modulus less than 23.68 GPa), and an exploitable piezoelectricity ($d_{34} = 5.24 \text{ pC N}^{-1}$). Moreover, its potential piezoelectric generation application was demonstrated by an easily fabricated DAP-M4/TPU (thermoplastic polyurethane) composite film with an open-circuit voltage of 3.5 V and a short-circuit current of 0.5 μA . Being a novel energetic ferroelectric material with simultaneously excellent energetic and optical–electrical properties, DAP-M4 provides an attractive possibility for assembling highly integrated functional and self-destructive devices, and inspires the design of next-generation multi-functional materials based on diverse molecular components.

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Introduction

Molecule-based piezoelectric materials, differing from conventional inorganic piezoelectric crystals such as lead zirconate titanate (PZT), barium titanate (BaTiO₃), and zinc oxide (ZnO),^{1–10} generally feature a piezoelectric effect benefiting from polar molecular components, which can undergo a special polarization conversion under proper stress. Taking advantage of their tunable structure, low production cost, “soft” texture, and degradability, molecule-based piezoelectric materials have attracted increasing attention in recent years.^{1,11–13} For a given molecule-based piezoelectric, it is currently possible to predict its mechanical and piezoelectric properties using first-principles calculations of density functional theory (DFT) and density functional perturbation theory (DFPT), respectively.^{14–27} Recently, these calculations have greatly improved the understanding of the origin of crystal mechanics and piezoelectricity for several piezoelectrics, such as (*R*)-(*S*)-(1-methylbenzylaminium))PbBr₃,

(Hmdabco)(NH₄)X₃ (Hmdabco²⁺ = 1-methyl-1,4-diazabicyclo-[2.2.2]octane-1,4-diium, X = Cl, Br, or I), and (benzyltrimethylammonium)₂CoBr₄.^{19,20,25,26} Moreover, with the advantage of lower manufacturing costs when compared with conventional inorganic piezoelectric crystals, several molecule-based piezoelectric crystals have been assembled into piezoelectric generation devices for harvesting environmental vibrational energy to meet the requirements for self-energy supply in low-power devices.^{11,12,22,23,26,28–38}

It was found that ferroelectrics, belonging to a class of piezoelectrics in which the direction of spontaneous polarization can be reversed by an applied electric field¹³ and following a ferroelectric group–subgroup relationship during phase transitions,^{39,40} generally have a higher piezoelectric effect than non-ferroelectric ones, and are thus more desired in seeking advanced piezoelectric materials.^{40–43} Since the discovery of Rochelle salt, molecule-based ferroelectrics have been considered attractive and environmentally friendly functional piezoelectric materials, and the metal-free piezoelectric materials are believed to be even more flexible, tunable, biodegradable, and biocompatible, e.g., (Hmdabco)(NH₄)I₃.^{13,40} Among the numerous metal-free molecule-based ferroelectric crystals discovered in the past years,^{3,6,13,36,44–48} certain perchlorate-based ones have potential energetic properties from their rapid decomposition capacities.^{3,45,47} Such a type of material simultaneously exhibits excellent electric properties, for self-energy supply or

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information detection/processing, as well as good energetic properties, for self-destruction on demand, providing an attractive possibility to design highly integrated functional and self-destructive devices for the military. Nevertheless, the application of most of the known perchlorate-based ferroelectric crystals is limited due to their poor thermal stabilities or their high hygroscopicities under ambient conditions.^{3,32,33,45}

We recently reported a family of metal-free perchlorate-based energetic materials possessing perovskite-type structures,⁴⁹ among which (Hmdabco)(NH₄)(ClO₄)₃ (called DAP-M4) has a good energetic performance and a rather high thermal stability (decomposition peak temperature $T_d = 364$ °C).⁴⁹ More interestingly, single-crystal structural analysis at 223 K preliminarily indicated that DAP-M4 crystallizes in a polar space group $P2_1$, implying potential ferroelectric properties. Herein, we comprehensively studied the structural phase transitions for DAP-M4, and proved that DAP-M4 is a rare room-temperature energetic ferroelectric, by means of thermal analyses, variable-temperature single-crystal X-ray diffraction, variable-temperature second-harmonic-generation (SHG), piezo-response force microscopy (PFM), and first-principles calculations. Moreover, we found that the unique intermolecular interactions between the ternary molecular components endow DAP-M4 with a high moisture stability in air, differing from that of other known perchlorate-based ferroelectrics. Based on the piezoelectric characteristic of DAP-M4, we fabricated a DAP-M4/TPU (TPU = thermoplastic polyurethane) composite film to demonstrate its piezoelectric generation for harvesting environmental vibrational energy.

Experimental

Syntheses

DAP-M4, (Ac)ClO₄ (acetamidinium perchlorate), (Im)ClO₄ (imidazolium perchlorate), and (Hdabco)ClO₄ (1,4-diazabicyclo[2.2.2]octan-1-ium perchlorate) were synthesized according to methods reported in the literature.^{3,45,49,50} The product purity was verified by powder X-ray diffraction (PXRD) patterns (Fig. S1 and S6, ESI†).

Materials and instruments

All chemicals were commercially available and used without further purification. PXRD patterns were recorded using a Bruker D8 ADVANCE X-ray powder diffractometer (Cu K α , $\lambda = 1.54184$ Å). DSC measurements were performed by heating/cooling the powder samples at a rate of 10 K min⁻¹ on a TA DSC Q2000 instrument. The second-harmonic-generation (SHG) effect was measured using a XPL1064-200 instrument at a heating/cooling rate of 5 K min⁻¹. The temperature-dependent dielectric permittivity was performed for a tablet powder sample on a Tonghui TH2828A instrument at a frequency range from 50 to 1000 kHz with an applied electric field at 1 V. Ferroelectric hysteresis loops were measured on a Radiant Precision Premier II instrument. PFM measurements were performed by using a PFM mode on a Bruker Dimension Fast Scan Bio Atomic Force Microscope. The cross-sectional photographs and compositional analysis of the flexible films

were characterized by Zeiss Gemini 500 and Flat-QUAD EDS, respectively. The UV-vis spectrum was measured on a Perkin-Elmer (British) Lambda 950 spectrophotometer at room temperature. The band gap (E_g) was estimated by converting reflectance data into absorbance with the Kubelka–Munk equation: $(h\nu \cdot F(R_\infty))^{1/n} = A(h\nu - E_g)$.

Single-crystal X-ray diffraction analyses

Diffraction data were collected on a SuperNova single-crystal diffractometer by using Cu K α ($\lambda = 1.54184$ Å) radiation. Absorption corrections were applied by using the multi-scan program CrysAlisPro. All structures were solved by the direct methods and refined by the full-matrix least-squares technique with the SHELX program package on Olex.² Anisotropic thermal parameters were applied to all non-hydrogen atoms. The hydrogen atoms were generated geometrically. Crystal data and refinements for DAP-M4 are summarized in Table S1 (ESI†).

Hygroscopicity measurements

The hygroscopicity was determined by the weight gain method.⁵¹ About 2 g of ground test samples were initially dried to a constant weight (with a fluctuation less than 0.2 mg) and then placed in chambers at room temperature and a relative humidity of 43%, 67%, 86%, and 100%, respectively. The samples were weighed every 12 h. The moisture absorption rate ω was calculated by the following equation.

$$\omega = \frac{m_1 - m_0}{m_0} \times 100\%$$

where m_0 denotes the initial mass, g ; and m_1 denotes the mass after moisture absorption, g .

Piezoelectric generation

A powder sample (1.0 g) of DAP-M4 was added to a tetrahydrofuran solution (1 mL) containing 21.9 wt% TPU and stirred for 2 h. Then, the mixture was placed in a vacuum oven to drain the bubbles generated by stirring, before spreading it on the glass substrate. Finally, the 250 μ m-thick DAP-M4/TPU composite flexible film was obtained. A piezoelectric generator consisting of the DAP-M4/TPU composite film with both top and bottom copper tapes attached by conductive wires was fabricated. The piezoelectric generations were demonstrated by a magnetic shaker, and the generator device was operated by a periodic external force of 30 N from the shaker (shown in Fig. S14a, ESI†). The conductive wires from both of the electrodes were fixed through a cable and directly connected to a megger (Keithley 6517B) to collect the output voltage and current signal during the measurement.

Computational details

The elastic and piezoelectric constants were obtained by first-principles calculations based on density functional theory (DFT), which were performed using the Vienna *ab initio* simulation package (VASP). The energy cut-off was set to 500 eV, and the k -point mesh spanning scheme of Monkhorst–Pack was $3 \times 3 \times 2$. Local density approximation was used as the

exchange–correlation energy functional to optimize the atomic positions in different pressure conditions when the lattice parameters were fixed to the experimental values. The elastic stiffness constants were obtained by the finite-strain method with 0.015 Å of the maximum strain amplitude and six steps for each strain. The maximum force and the total energy converged to 0.02 eV Å^{−1} and 10^{−6} eV for a single atom, respectively. The zero-damping DFT-D3 method combined with the Grimme correlation was applied to explicate the discrete effects. The piezoelectric strain constants (d_{ij}) were obtained by the formula $d_{ij} = e_{ij} \times s_{ij}$, where e_{ij} (the piezoelectric stress tensor) was calculated using density functional perturbation theory (DFPT), and s_{ij} is the elastic compliance constant (the inverse matrix of the elastic stiffness constant). The band structure and partial density of states (PDOS) of DAP-M4 were obtained by DFT calculations, and the piezopotential was simulated by COMSOL.

Results and discussion

Two reversible structural phase transitions were detected by DSC curves during a heating/cooling cycle (Fig. 1), as indicated by two pairs of thermal anomalies at around 356/355 K and 361/358 K, respectively. The total entropy changes (ΔS) during the two-step phase transitions in the heating run were estimated to be 1.1 and 10.5 J mol^{−1} K^{−1}, respectively. For convenience, we labeled the phase at below 356 K, between 356 K and 361 K, and above 361 K as RTP, ITP, and HTP, respectively.

To visually understand these structural phase transitions, variable-temperature single-crystal X-ray diffractions were performed at 293, 358, and 393 K for RTP, ITP, and HTP, respectively (Fig. 2). Crystal data as well as details of data collection and refinements for DAP-M4 are summarized in Table S1 (ESI[†]). In general, DAP-M4 adopts an ABX₃-type perovskite structure, in which each B-site cation (NH₄⁺) is surrounded by six X-site anions (ClO₄[−]) to form a three-dimensional inorganic framework consisting of cages occupied by A-site organic cations (Hmdabco²⁺). The structure collected at 293 K (RTP)

crystallizes in space group $P2_1$ with $a = 10.20664$ Å, $b = 11.00567$ Å, $c = 14.84750$ Å, and $\beta = 90.1263^\circ$, which is consistent with the our previously reported structure at 223 K, except that the cell at 293 K is slightly expanded.⁴⁹ In the RTP, the (NH₄)(ClO₄)₆ octahedra are slightly distorted, and the A-site organic cations are crystallographically ordered.

The two-step structural phase transitions were found to be highly associated with the gradually activated molecular dynamics of A-site Hmdabco²⁺ cations with increasing temperature. In detail, the structure collected at 358 K (ITP) belongs to the trigonal space group $R\bar{3}m$ with $a = 10.6675$ Å and $c = 13.0585$ Å, in which the organic cations are 12-fold dynamically disordered in almost arbitrary orientations and the (NH₄)(ClO₄)₆ octahedra become regular.⁵² With further heating, the HTP belongs to the cubic space group $Pm\bar{3}m$ with $a = 7.5679$ Å, which is a prototype of a typical perovskite structure without any deformation, and, accordingly, the Hmdabco²⁺ cations, NH₄⁺ cations, and ClO₄[−] bridges are 48-fold, 48-fold, and 16-fold dynamically disordered, respectively. Such stepwise changes in the molecular dynamic motions agree with the aforementioned entropy changes during phase transitions observed in DSC curves. It is worth noting that the phase transition from ITP to RTP belongs to an Aizu notation of $3mF2$, which is a ferroelectric transition with a number change of symmetry elements from 12 (E , $2C_3$, $3C_2'$, i , $2S_6$, and $3\sigma_d$) to 2 (E and C_2), suggesting DAP-M4 is an uncommon multi-axial ferroelectric with three ferroelectric axes in RTP.⁵³

To further clarify the ferroelectric properties of RTP, a variable-temperature SHG measurement was performed on the polycrystalline sample of DAP-M4 (shown in Fig. 3a). The SHG intensity at 298 K (RTP) is about 0.23 times that of the reference KH₂PO₄. When heated to above 356 K (ITP), the SHG intensity decreases to almost zero, *i.e.*, the SHG is silenced. Such a SHG switch behavior fits well with the space group variation between the non-centrosymmetric RTP ($P2_1$) and the centrosymmetric ITP ($R\bar{3}m$) observed in single-crystal X-ray diffraction. In addition, the temperature dependence of the real part of the dielectric permittivity (ϵ') was evaluated in the range of 295–392 K on a powder-pressed sample of DAP-M4 (as shown in Fig. 3b). It exhibits a reversible step-like dielectric response between RTP and HTP in a heating–cooling cycle, which is an indication of an improper ferroelectric.^{41,52}

Moreover, the variable-temperature electric polarization *versus* electric field (P – E) hysteresis loops (Fig. S2, ESI[†]) were measured on a single crystal by applying an electric field along its b axis (*i.e.*, the polarization axis), revealing that the polarization value at an electric field of 5 kV cm^{−1} was significantly decreased from 2.31 μC cm^{−2} at 293 K (ferroelectric RTP) to 0.52 μC cm^{−2} at 358 K (paraelectric ITP). It should be noted that the spontaneous polarization measured at 293 K was not saturated yet under an electric field of 5 kV cm^{−1}, owing to the relatively larger electric field required for overcoming the spatial resistance to rotate the Hmdabco²⁺ cations.

To gain insight into the ferroelectric domain distribution in RTP, both vertical and lateral PFM (VPFM and LPFM) mappings⁵⁴ were investigated on the same region (5 μm × 5 μm) of the DAP-M4

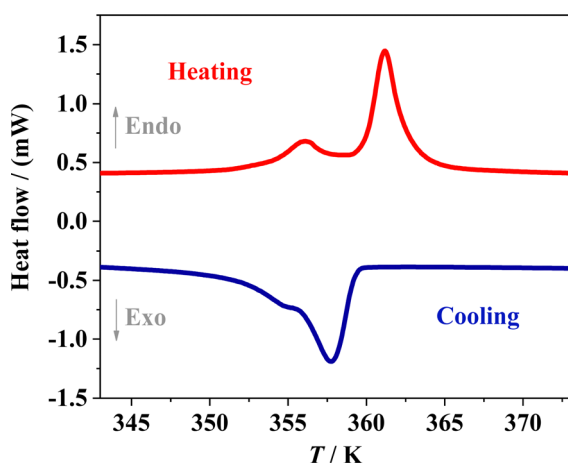


Fig. 1 DSC curves for DAP-M4 during a heating/cooling cycle.

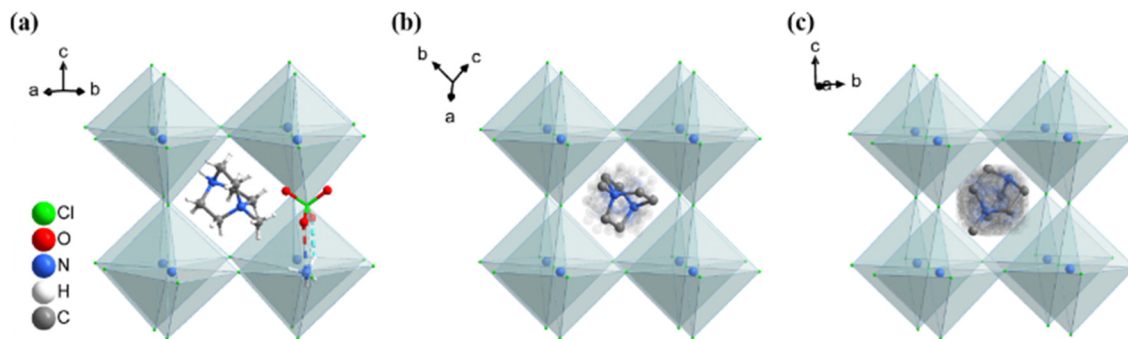


Fig. 2 Crystal structure of DAP-M4 at (a) RTP, (b) ITP, and (c) HTP. Hydrogen atoms are omitted for clarity.

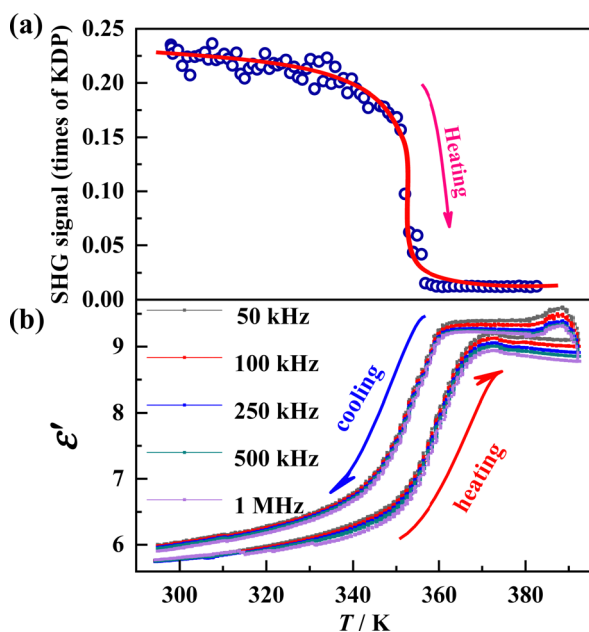


Fig. 3 (a) Temperature-dependence of the SHG signal in a heating run and (b) real part of the dielectric permittivity during a cooling–heating cycle measured under an ac electric field for DAP-M4.

single crystal by applying a voltage perpendicular to the crystal plane (shown in Fig. S3, ESI†). Obviously, a bipolar domain pattern emerged in the VPFM amplitude and phase, indicating the presence of two different 180° polarization directions in the region.^{8,52} Similarly, the LPFM amplitude image shows a bipolar domain distribution while the LPFM phase signal is blurred and distorted. The distinctive domain distributions of the VPFM and LPFM mappings suggested that DAP-M4 is an anti-parallel polarized ferroelectric along the polar axis. Therewith, to manifest the polarization reversal behavior, the ultrafast reversal trend of DAP-M4 ferroelectric polarization clearly emerges (Fig. 4). The tip bias was separately applied at -1 V, 0 V, and $+1$ V, respectively, in three equal regions, which results in two significant reversals in the polarization direction visible in the VPFM and LPFM phases (shown in Fig. 4c, f and Fig. S4, ESI†). Moreover, when the applied voltage was 8 V (E is *ca.* 57 kV cm $^{-1}$), a slender phase loop and an amplitude loop (Fig. 4d) representing the ultrafast polarization reversal of domains

were observed. In short, these observations confirmed the fast reversal of ferroelectric polarization for DAP-M4, distinguishing it from other piezoelectric/pyroelectric materials. To the best of our knowledge, DAP-M4 is the first energetic ferroelectric based on ternary perchlorate salt.

The hygroscopicity of DAP-M4 was further investigated at ambient temperature and under 43%, 67%, 86%, 100% relative humidity (RH), respectively. For comparison, three known potential energetic ferroelectric and polar materials based on binary perchlorate salts, *i.e.*, (Ac)ClO $_4$ (acetamidinium perchlorate),⁵⁰ (Im)ClO $_4$ (imidazolium perchlorate),^{45,47} and (Hdabco)ClO $_4$ (1,4-diazabicyclo-[2.2.2]octan-1-ium perchlorate),³ were also investigated under the same conditions. The results (Fig. S5, ESI†) indicated well that DAP-M4 has a much higher moisture stability than the other three compounds. For instance, when staying at 67% RH for 144 hours, (Ac)ClO $_4$, (Im)ClO $_4$, and (Hdabco)ClO $_4$ increased by 1.97%, 0.26% and 0.044% in weight, respectively, while DAP-M4 increased by only 0.01%, with error bars of about 0.02%. Even under 100% RH for after 144 hours, as shown in Fig. 5, DAP-M4 only achieved a 0.01% weight increase, which is far below that of (Ac)ClO $_4$ (2.96%), (Im)ClO $_4$ (0.87%), and (Hdabco)ClO $_4$ (0.3%). In short, compared with these binary perchlorate ferroelectric compounds, DAP-M4, as a ternary perchlorate salt, has a good non-humidity dependence and maintains ultra-low hygroscopicity even at 100% RH, and is preferable to its un-methylated prototype compound (*i.e.*, (H $_2$ dabco)(NH $_4$)(ClO $_4$) $_3$ called DAP-4) with a weight gain of 0.06% at 90% RH.^{51,55}

To determine the mechanism for the moisture stability of DAP-M4, Hirshfeld surface analysis was performed for the organic Hmdabco $^{2+}$ cation in RTP (shown in Fig. S7, ESI†). The H atoms from both the Hmdabco $^{2+}$ cation and the NH $_4^+$ cation interact with the O atoms from ClO $_4^-$ *via* N/C–H \cdots O hydrogen bonds, such that the cations and anions alternately complement each other and closely pack in a dense crystal structure. Such complementing inner hydrogen bonds, together with the hydrophobic methyl groups, prevent the H and O atoms in NH $_4^+$ and ClO $_4^-$ from forming strong hydrogen bonds with water molecules in the air, thus endow DAP-M4 with ultra-low hygroscopicity.^{49,55,56}

The UV–vis absorption spectrum was measured on the polycrystalline sample (Fig. S8a, ESI†), and the partial density of states (PDOS) and the band structure were calculated

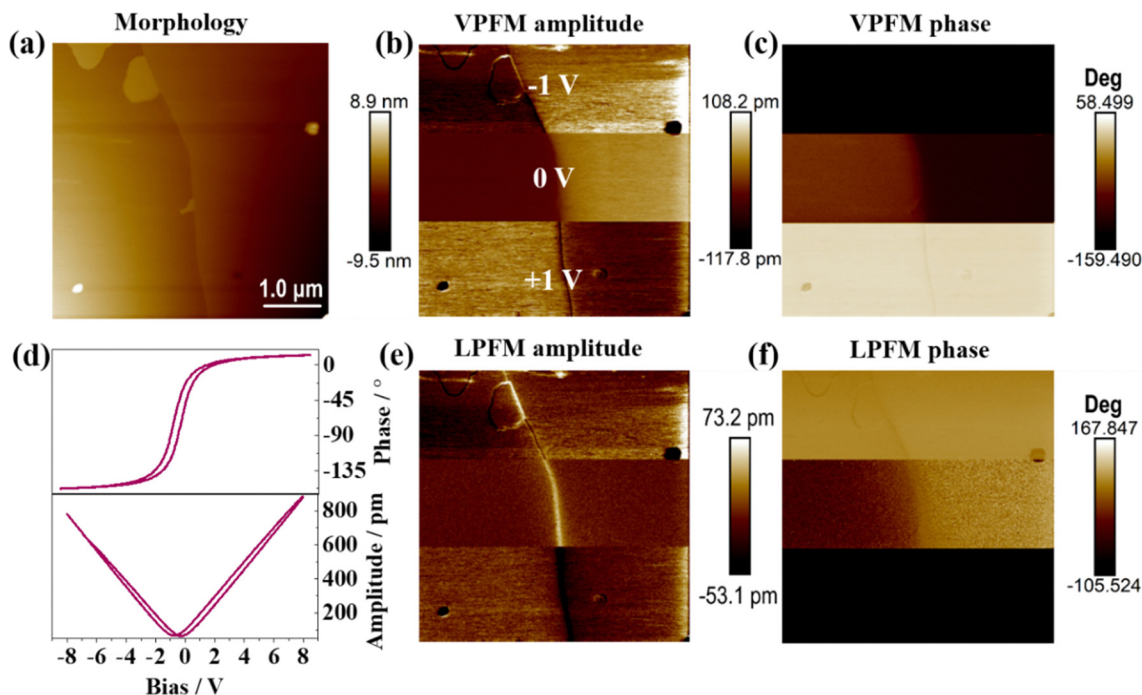


Fig. 4 (a) Morphology image, and (b and c) vertical and (e and f) lateral PFM images of the crystal surface for DAP-M4. (d) Phase–voltage hysteresis loop and amplitude–voltage loop for a selected area on the crystal surface.

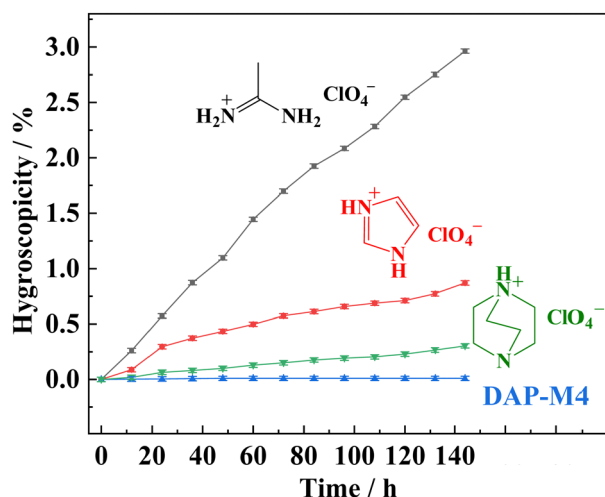


Fig. 5 Hygroscopic curves of (Ac)ClO₄, (Im)ClO₄, (Hdabco)(ClO₄), and DAP-M4 at room temperature under 100% RH.

(Fig. S8b and c, ESI[†]) based on the single-crystal structure to estimate the band gap for DAP-M4. The UV-vis absorption spectrum indicated progressively absorbing edges at about 230 nm, and a band gap of 5.40 eV was estimated (the inset plot in Fig. S8a, ESI[†]). The conduction-band minimum (CBM) and the valence-band maximum (VBM) lie in different positions in the Brillouin zone, indicating that DAP-M4 is an indirect band gap semiconducting material, and the band gap calculated from the difference between CBM and VBM is 5.40 eV, which is in good agreement with the value obtained by the UV-vis absorption spectrum. As revealed by the PDOS, the H-1s

states overlap fully with C-2s2p and N-2s2p in the energy ranges of −21 to 16.5 eV, indicating strong covalent interactions of the C–H and N–H. The CBM and VBM are mainly from the O-2p states and the Cl-3p states, respectively. Namely, the band gap of DAP-M4 is mainly determined by the ClO₄[−] anions. These facts indicated that DAP-M4 has an ultrawide band gap, exceeding GaN (3.4 eV) and (benzylammonium)₂PbCl₄ (3.65 eV), but slightly lower than diamond (5.47 eV), and offers potential applications in extreme environments.^{57–60}

As an energetic ferroelectric material, DAP-4 may serve as a promising molecule-based piezoelectric material with excellent electro-mechanical coupling properties. For a piezoelectric material, the elastic properties are of particular importance as they reflect not only the resistance to stresses in various directions, but also facilitate further characterization of the intrinsic piezoelectric properties of the crystal. Nevertheless, little was known about the elastic properties of the promising metal-free piezoelectric materials.²⁵ In order to understand the elastic properties of DAP-M4, its elastic stiffness constants C_{ij} (in GPa) were calculated by DFT and are matrixed as follows:

$$\begin{pmatrix} 24.783 & 8.6 & 9.27 & 0 & -0.476 & 0 \\ 8.6 & 25.92 & 12.685 & 0 & -0.18 & 0 \\ 9.27 & 12.685 & 27.441 & 0 & 1.129 & 0 \\ 0 & 0 & 0 & 9.197 & 0 & -1.033 \\ -0.476 & -0.18 & 1.129 & 0 & 8.191 & 0 \\ 0 & 0 & 0 & -1.033 & 0 & 6.981 \end{pmatrix}$$

Based on the above C_{ij} values, the elastic properties, including Young's modulus (E), shear modulus (G), and Poisson's ratio (ν), are graphically depicted by the visualization

algorithm, as shown in Fig. S9 (ESI[†]), and the relevant extreme values are listed in Table S2 (ESI[†]). Young's modulus (E) characterizes the resistance of the crystal elastic deformation, and its maximum value (E_{\max}) and minimum value (E_{\min}) are 23.68 GPa and 17.08 GPa, respectively. For example, as shown in Fig. S10 (ESI[†]), along the $\langle -1-10 \rangle$ direction, the Cl atoms in the ClO_4^- anions are constituted at different angles to the N atom in the adjacent NH_4^+ ions, exhibiting spatial geometric asymmetry, and the distorted $(\text{NH}_4)(\text{ClO}_4)_6$ octahedra bring about different Young's moduli of the DAP-M4 crystal along different directions, *i.e.*, an anisotropic mechanical response. Likewise, for the shear modulus, representing the resistance of the material to shear deformation, the maximum value (G_{\max}) is 9.60 GPa and the minimum value (G_{\min}) is 6.57 GPa. Such a relatively minor difference between the maximum and minimum shear modulus could be mainly ascribed to the dense cubic crystal structure in DAP-M4. Namely, DAP-M4 has an advantage over metal-free $(\text{Hmdabco})(\text{NH}_4)\text{I}_3$ ($E_{\max} = 19$ GPa, $E_{\min} = 6.39$ GPa) and discrete $(\text{benzyltrimethylammonium})_2\text{-CoBr}_4$ ($E_{\max} = 17.6$ GPa, $E_{\min} = 4.11$ GPa),^{25,26} but also exhibits softer mechanical properties than $(\text{Hmdabco})\text{KI}_3$ ($E_{\max} = 28.2$ GPa, $E_{\min} = 22.5$ GPa).²⁵

With its "soft" mechanical properties, when DAP-M4 is subjected to an external stress, it tends to generate a large deformation and then a large piezoelectricity. The piezoelectric strain coefficients matrix obtained from the DFPT calculations demonstrated that the ion contribution is greater than the electric contribution to the piezoelectric stress tensor e_{ij} (Table S3, ESI[†]). Precisely, the motions of positive and negative ions under an applied electric field are mainly responsible for the potential shift. The 3D and 2D representations of the piezoelectric strain constants d_{ij} are shown in Fig. 6a and b, and the specific values of d_{ij} (unit of pC N^{-1}) matrix are as follows.

$$\begin{pmatrix} 0 & 0 & 0 & -0.71 & 0 & -0.1 \\ -0.42 & -0.86 & -0.12 & 0 & 0.01 & 0 \\ 0 & 0 & 0 & 5.24 & 0 & 0.77 \end{pmatrix}$$

In the d_{ij} matrix, the shearing piezoelectric constant d_{34} is 5.24 pC N^{-1} , which is 6 times larger than d_{14} of quartz.²⁶ The origin of piezoelectricity can be rationalized by the polar structure of RTP. In detail, since non-polar NH_4^+ and ClO_4^- of RTP are perfectly symmetrically aligned along the a , b , and c axes, the centers of positive and negative charges remain aligned when stress is applied, whereas the methyl group and the non-centrosymmetric arrangement of Hmdabco^{2+} cations allow the perturbation of the external strain to easily split the centers of the positive and negative charges, producing a net dipole moment along the b -axis direction and generating a noticeable d_{34} .^{16,20,21} The shear piezoelectric effects enable DAP-M4 to be a promising piezoelectric crystal to be assembled cooperatively with other materials for mechanical/electronic transformation in a power generation device.⁶¹

To demonstrate the potential piezoelectric generation applications for DAP-M4, a DAP-M4/TPU composite film (shown in

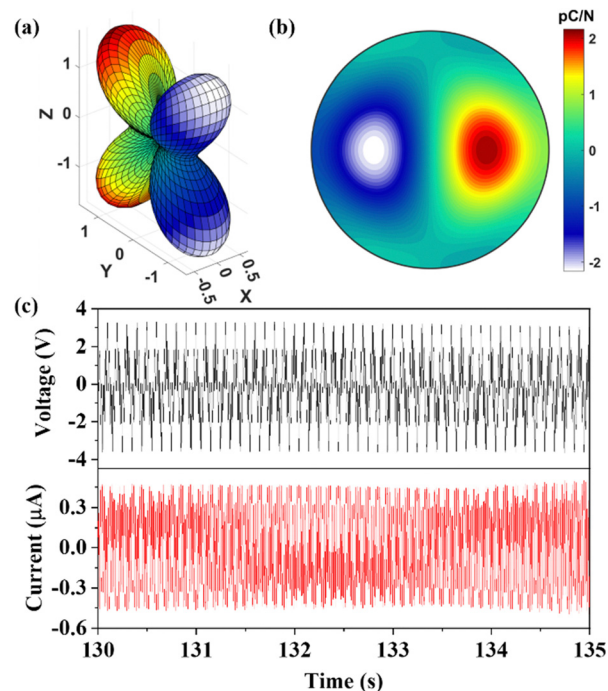


Fig. 6 (a) 3D and (b) 2D surface rendering representations of the piezoelectric strain tensors for DAP-M4. (c) Output of the open-circuit voltage (V_{oc}) and short-circuit current (I_{sc}) of DAP-M4/TPU film from 130 s to 135 s.

Fig. S11, ESI[†]) was fabricated by integrating DAP-M4 crystal particles into thermoplastic polyurethane (TPU), which has good elasticity and toughness to serve as a gelling agent.⁶² As shown in Fig. S12 and S13 (ESI[†]), comparative XRD patterns and the cross-sectional morphology of the DAP-M4/TPU composite films indicated that the TPU acts as an adhesive to bind DAP-M4 particles. In addition, an open-circuit voltage (V_{oc}) of about 3.5 V and a short-circuit current (I_{sc}) of about $0.5 \mu\text{A}$ were obtained by tapping the device with a sandwich structure consisting of a composite film layer and two copper foils within 600 s (as shown in Fig. S14, ESI[†]). For reference, the neat TPU polymer has a V_{oc} of 200 mV and a negligible I_{sc} value.⁶³ Moreover, the simulated piezoelectric potential maximum is relatively close to V_{oc} (as shown in Fig. S14c, ESI[†]). To more clearly represent the signal trends of V_{oc} and I_{sc} , the relatively stable piezoelectric generation of the DAP-M4/TPU film in 5 s (from 130 s to 135 s) is shown in Fig. 6c. Comparatively, the sensitivity performance of the DAP-M4/TPU film for piezoelectric generation (105 mV kPa^{-1}) is superior to a composite based on imidazolium perchlorate embedded in a bacterial cellulose hydrogel (4.24 mV kPa^{-1}).³²

Conclusions

In summary, we proved that the energetic material DAP-M4 is a rare room-temperature moisture-stabilized ferroelectric crystal simultaneously exhibiting a low hygroscopicity, an ultrawide band gap, "soft" mechanical properties, and an exploitable piezoelectricity. By taking advantage of these properties, we

fabricated a DAP-M4/TPU composite film, which exhibits a V_{oc} of about 3.5 V and a I_{sc} of about 0.5 μ A, thus demonstrating the potential of DAP-M4 to be used for self-energy supply or information detection/processing. The results suggest that DAP-M4, as a scarce instance of an energetic ferroelectric material simultaneously exhibiting excellent energetic and optic-electric properties, provides an attractive possibility for integrated functional and self-destructive devices in high-tech military equipment. The present studies on such types of novel energetic ferroelectric materials may inspire the design of next-generation integrated functional materials based on diverse molecular/ionic components.

Conflicts of interest

There are no conflicts to declare.

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